

Single Phase Glass Passivated Silicon Bridge Rectifier

V_{RRM} = 50 V - 400 V
I_O = 4 A

Features

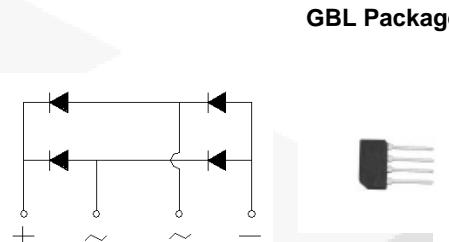
- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- This series is UL listed under the Recognized
- Glass passivated chip junction
- High case dielectric strength
- Typical I_R less than 0.1 A
- High surge current capability
- Ideal for printed circuit boards
- Not ESD Sensitive

Mechanical Data

Case: Molded plastic body over passivated junctions

Terminals: Plated leads, solderable per MIL-STD-750 Method 2026.

Weight: 0.071 oz, 2.0 g



Maximum ratings at T_c = 25 °C, unless otherwise specified

Parameter	Symbol	Conditions	GBL005	GBL01	GBL02	GBL04	Unit
Repetitive peak reverse voltage	V _{RRM}		50	100	200	400	V
RMS reverse voltage	V _{RMS}		35	70	140	280	V
DC blocking voltage	V _{DC}		50	100	200	400	V
Operating temperature	T _j	-55 to 150	°C				
Storage temperature	T _{stg}	-55 to 150	°C				

Electrical characteristics at T_c = 25 °C, unless otherwise specified

Single phase, half sine wave, 60 Hz, resistive or inductive load

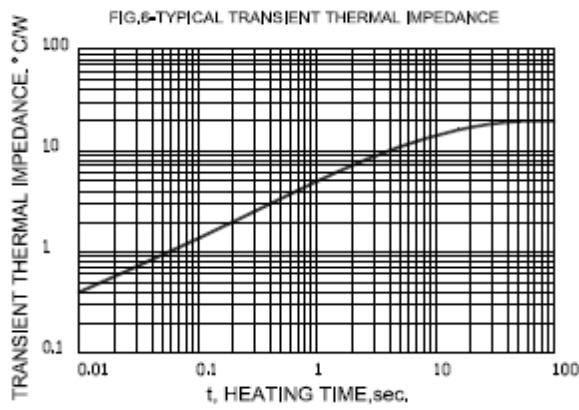
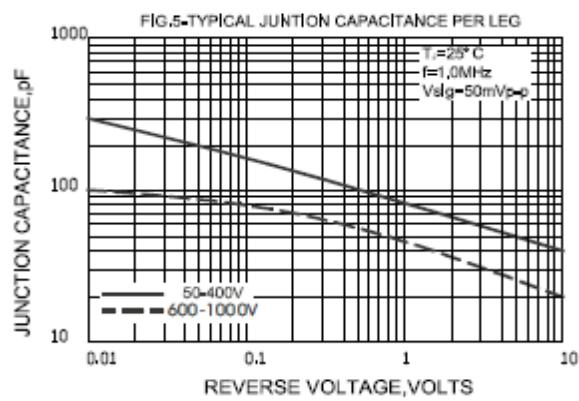
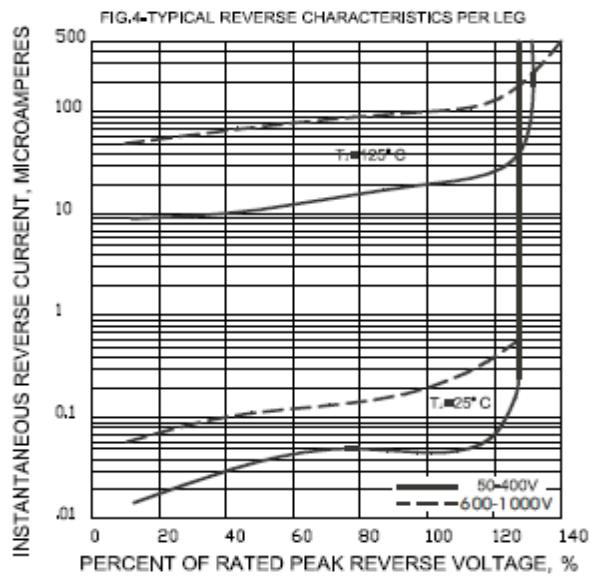
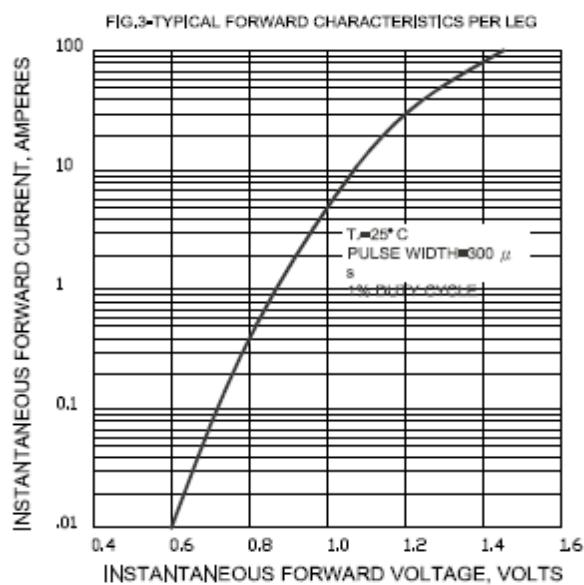
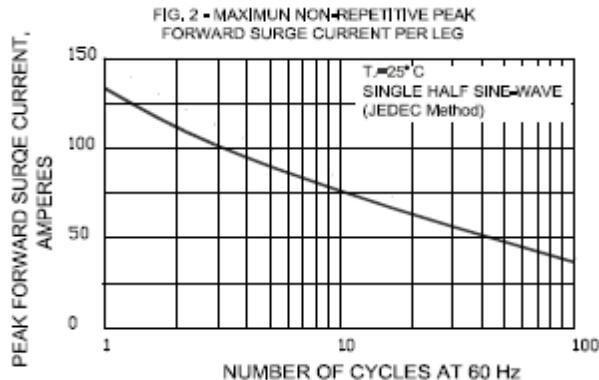
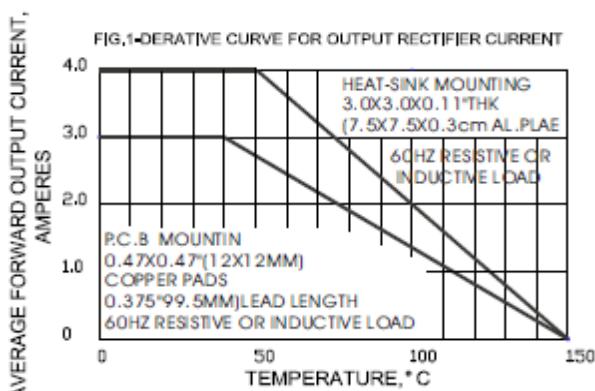
For capacitive load derate current by 20%

Parameter	Symbol	Conditions	GBL005	GBL01	GBL02	GBL04	Unit
Maximum average forward rectified current	I _O	T _c = 50 °C (Note 1) T _c = 40 °C (Note 2)	4.0 3.0	4.0 3.0	4.0 3.0	4.0 3.0	A
Peak forward surge current	I _{FSM}	t _p = 8.3 ms, half sine	135	135	135	135	A
Maximum instantaneous forward voltage drop per leg	V _F	I _F = 4 A	1.1	1.1	1.1	1.1	V
Maximum DC reverse current at rated DC blocking voltage per leg	I _R	T _a = 25 °C T _a = 125 °C	5 500	5 500	5 500	5 500	μA
Rating for fusing	I ² t	t < 8.3 ms	75	75	75	75	A ² sec
Typical junction capacitance per leg (Note 3)	C _j		95	95	95	95	pF
Typical thermal resistance per leg	R _{θJA} R _{θJL}	(Note 1) (Note 2)	22 3.5	22 3.5	22 3.5	22 3.5	°C/W

¹ - Unit mounted on 3.0" x 3.0" x 0.11" (75 mm x 75 mm x 3 mm) Al plate

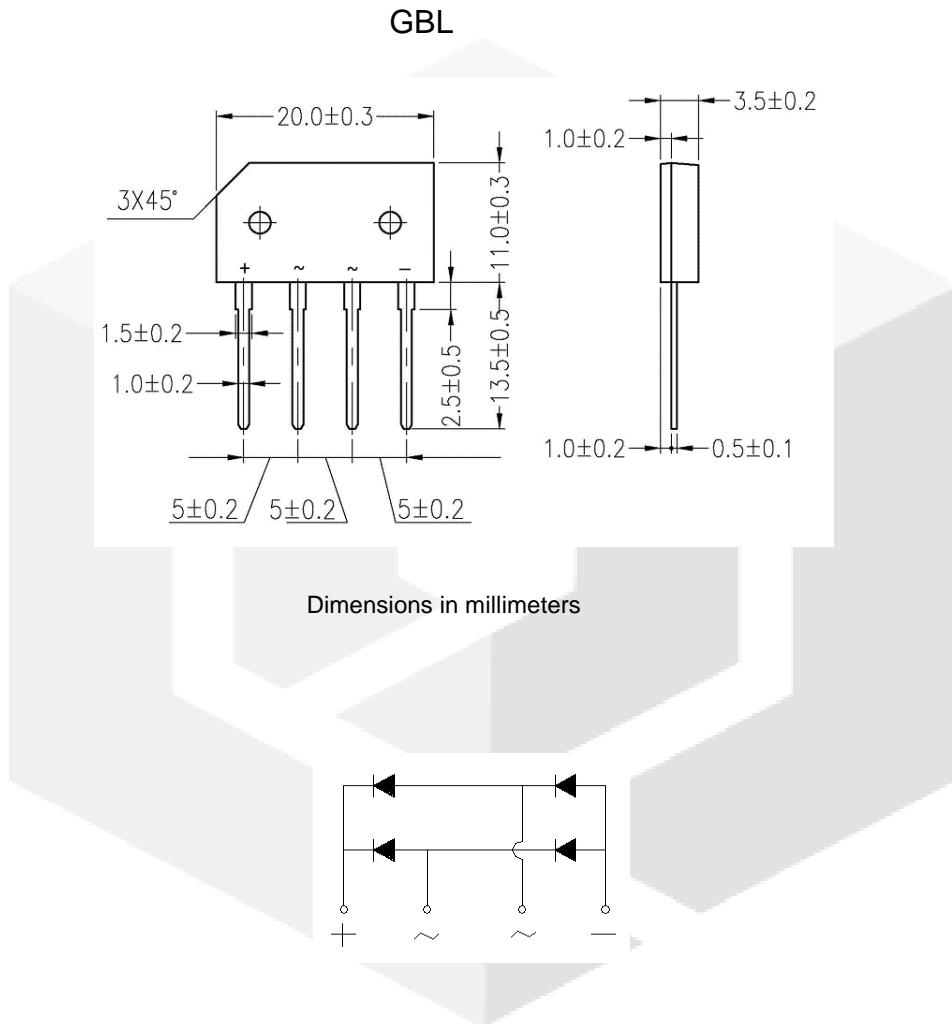
² - Unit mounted on P.C.B. At 0.375" (9.5 mm) lead length and 0.5" x 0.5" (12 mm x

³ - Measured at 1.0 MHz and applied reverse bias of 4.0 V



Package dimensions and terminal configuration

Product is marked with part number and terminal configuration.



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